

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

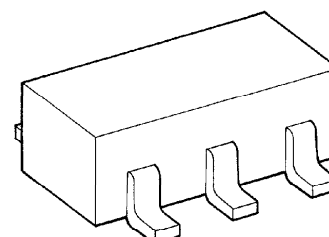
TC7SZU04F, TC7SZU04FU**INVERTER (UNBUFFER)****FEATURES**

- High Output Drive : $\pm 16\text{mA}$ (Typ.) @ $V_{CC}=4.5\text{V}$
- Super High Speed Operation : t_{PD} 2.4ns (Typ.)
@ $V_{CC}=5\text{V}$, 50pF
- Operation Voltage Range : $V_{CC}(\text{opr})=1.8\sim 5.5\text{V}$

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

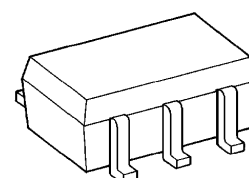
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	$-0.5\sim 6$	V
DC Input Voltage	V_{IN}	$-0.5\sim 6$	V
DC Output Voltage	V_{OUT}	$-0.5\sim V_{CC}+0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 50	mA
DC V_{CC} / Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	$-65\sim 150$	$^\circ\text{C}$
Lead Temperature (10s)	T_L	260	$^\circ\text{C}$

TC7SZU04F



SSOP5-P-0.95

TC7SZU04FU



SSOP5-P-0.65A

Weight

SSOP5-P-0.95 : 0.016g (Typ.)
SSOP5-P-0.65A : 0.006g (Typ.)

980910EBA1

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DC ELECTRICAL CHARACTERISTICS

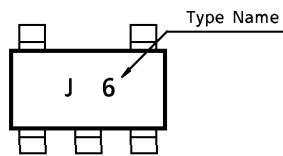
CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V _{IH}		1.8 – 2.7	0.85 × V _{CC}	—	—	0.85 × V _{CC}	—	V
			3.0 – 5.5	0.8 × V _{CC}	—	—	0.8 × V _{CC}	—	
Low-Level Input Voltage	V _{IL}		1.8 – 2.7	—	—	0.15 × V _{CC}	—	0.15 × V _{CC}	V
			3.0 – 5.5	—	—	0.2 × V _{CC}	—	0.2 × V _{CC}	
High-Level Output Voltage	V _{OH}	V _{IN} = V _{IL}	I _{OH} = -100 μA	1.8	1.6	1.8	—	1.6	V
				2.3	2.1	2.3	—	2.1	
				3.0	2.7	3.0	—	2.7	
				4.5	4.0	4.4	—	4.0	
			I _{OH} = -4mA	2.3	1.9	2.14	—	1.9	
			I _{OH} = -8mA	3.0	2.4	2.75	—	2.4	
			I _{OH} = -12mA	3.0	2.3	2.61	—	2.3	
Low-Level Output Voltage	V _{OL}	V _{IN} = V _{IH}	I _{OH} = 100 μA	1.8	—	0	0.2	—	V
				2.3	—	0	0.2	—	
				3.0	—	0	0.3	—	
				4.5	—	0	0.5	—	
			I _{OH} = 4mA	2.3	—	0.1	0.3	—	
			I _{OH} = 8mA	3.0	—	0.17	0.4	—	
			I _{OH} = 12mA	3.0	—	0.25	0.55	—	
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND	0 – 5.5	—	—	±1	—	±10	μA
Quiescent Supply Current	I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	2	—	20	μA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

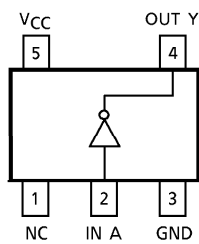
CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta = 25°C				Ta = - 40~85°C		UNIT
			V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time	t _{PLH} t _{PHL}	C _L = 15pF, R _L = 1MΩ	1.8	1.0	—	8.5	1.0	9.0	ns
			2.5 ± 0.2	0.8	—	6.2	0.8	6.5	
			3.3 ± 0.3	0.5	—	4.5	0.5	4.8	
			5.0 ± 0.5	0.5	—	3.9	0.5	4.1	
		C _L = 50pF, R _L = 500Ω	3.3 ± 0.3	1.0	—	6.0	1.5	6.5	
			5.0 ± 0.5	0.8	—	5.0	0.8	5.5	
Input Capacitance	C _{IN}		0 – 5.5	—	4.5	—	—	pF	
Power Dissipation Capacitance	C _{PD}	(Note 1)	3.3	—	6.3	—	—	—	pF
			5.5	—	9.5	—	—	—	

(Note 1) CPD is defined as the value of the internal equivalent capacitance which is Calculated from the operating current consumption without load.
Average operating current can be obtained by the equation.
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

MARKING



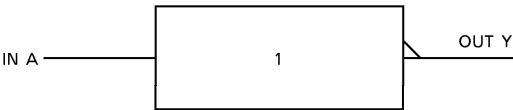
PIN ASSIGNMENT (TOP VIEW)



TRUTH TABLE

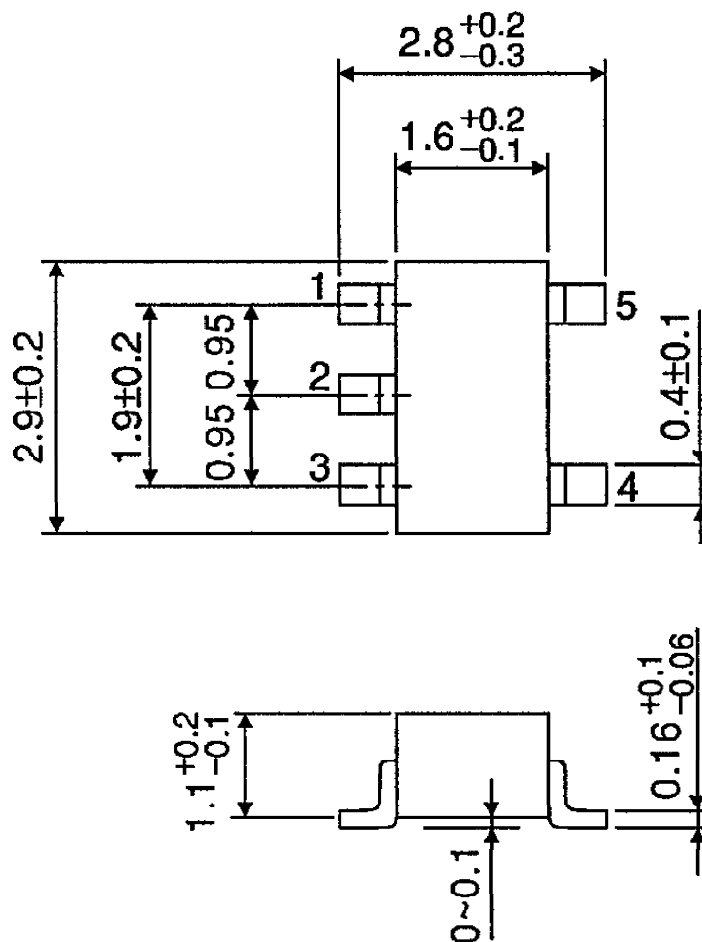
A	Y
L	H
H	L

LOGIC DIAGRAM



OUTLINE DRAWING
SSOP5-P-0.95

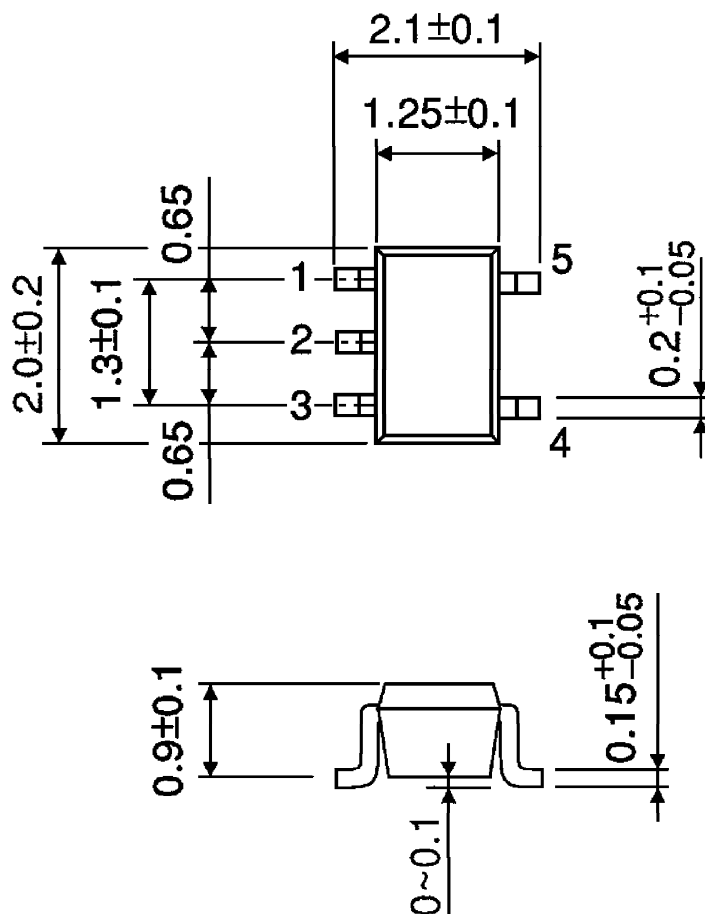
Unit : mm



Weight : 0.016g (Typ.)

OUTLINE DRAWING
SSOP5-P-0.65A

Unit : mm



Weight : 0.006g (Typ.)